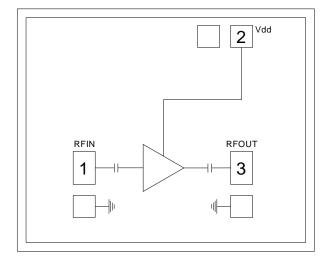
CMD305 6-16 GHz Driver Amplifier

Product Overview

The CMD305 is a broadband MMIC driver amplifier ideally suited for EW and communications systems where small size and low power consumption are needed. At 11 GHz the device delivers greater than 18 dB of gain and +21 dBm saturated output power at 24 % PAE from a single 5 V supply. The CMD305 is a 50 ohm matched design eliminating the need for external DC blocks and RF port matching. The CMD305 offers full passivation for increased reliability and moisture protection.

Functional Block Diagram



Key Features

- · Broadband Performance
- High Output Power
- Low Current Consumption
- Single Positive Supply Voltage
- Small Die Size

Ordering Information

Part No.	Description
CMD305	100 pcs in gel pack

Electrical Performance (V_{dd} = 5.0 V, T_A = 25° C, F = 11 GHz)

Parameter	Min	Тур	Max	Units
Frequency Range		6 - 16		GHz
Gain		18.5		dB
Input Return Loss		20		dB
Output Return Loss		9		dB
Output P1dB		20		dBm
Output Psat		21		dBm
Output IP3		34		dBm
Supply Current		100		mA



Absolute Maximum Ratings

Parameter	Rating
Drain Voltage, V _{dd}	5.5 V
RF Input Power	+10 dBm
Channel Temperature, Tch	150° C
Power Dissipation, Pdiss	650 mW
Thermal Resistance, Q _{JC}	100° C/W
Operating Temperature	-55 to 85° C
Storage Temperature	-55 to 150° C

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

Recommended Operating Conditions

Parameter	Min	Тур	Max	Units
V_{dd}	3.0	5.0	5.25	V
I _{dd}		100		mA

Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

Drain Current vs. Drain Voltage

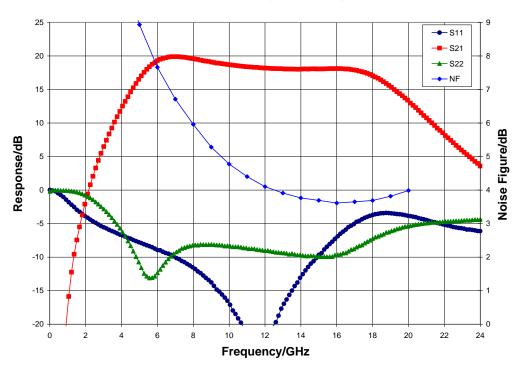
V _{dd} (V)	I _{dd} (mA)
3.0	65
4.0	85
5.0	100

Electrical Specifications (V_{dd} = 5.0 V, T_A = 25° C)

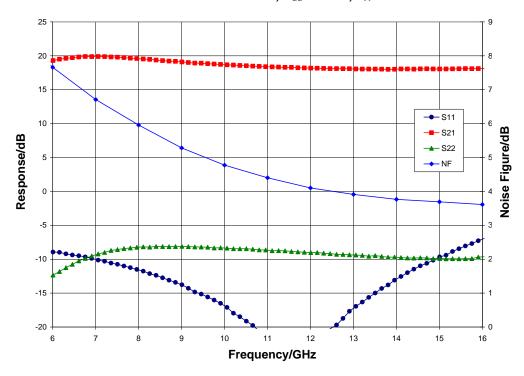
Parameter	Min	Тур	Max	Min	Тур	Max	Units
Frequency Range		6 - 9			9 - 16		GHz
Gain	16	19.5		15	18		dB
Noise Figure		6			4		dB
Input Return Loss		11			13		dB
Output Return Loss		9			9		dB
Output P1dB	16.5	20		17	20.5		dBm
Output Psat		21			21.5		dBm
Output IP3		33			34		dBm
Supply Current	70	100	130	70	100	130	mA
Gain Temperature Coefficient		0.010			0.010		dB/°C



Broadband Performance, $V_{dd} = 5.0 \text{ V}$, $T_A = 25^{\circ} \text{ C}$

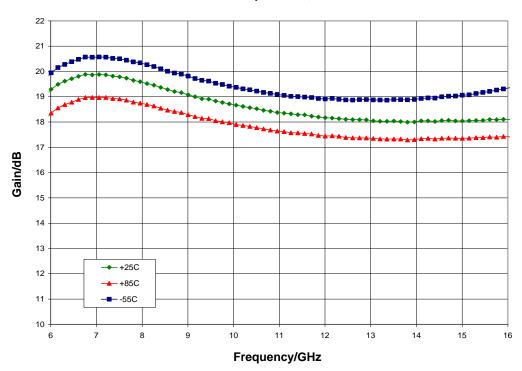


Narrow-band Performance, V_{dd} = 5.0 V, T_A = 25° C

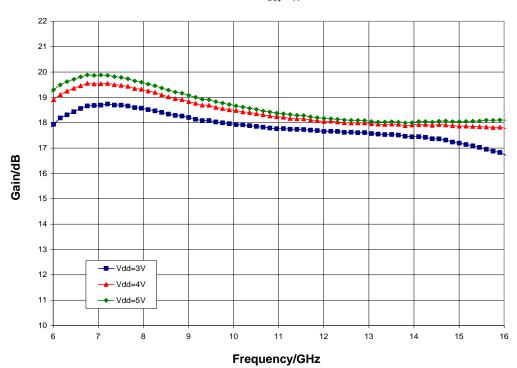




Gain vs. Temperature, $V_{dd} = 5.0 \text{ V}$

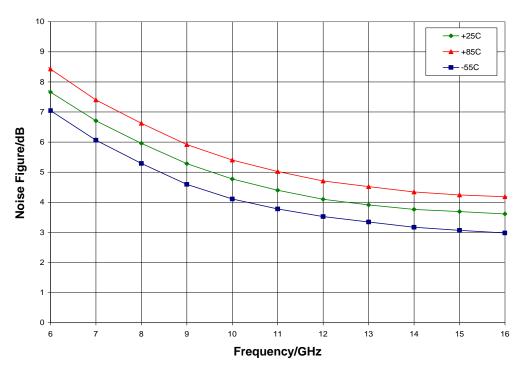


Gain vs. V_{dd} , $T_A = 25^{\circ} C$

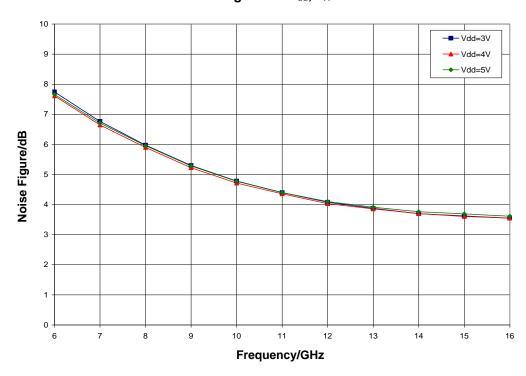




Noise Figure vs. Temperature, $V_{dd} = 5.0 \text{ V}$

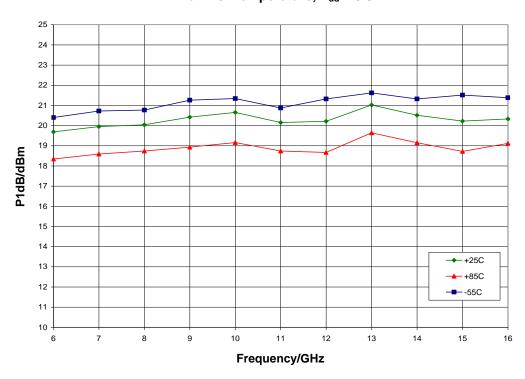


Noise Figure vs. V_{dd} , $T_A = 25^{\circ} C$

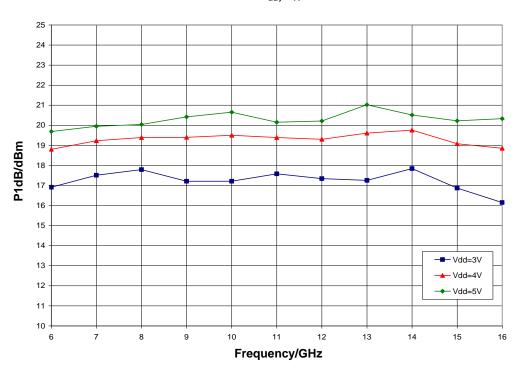




P1dB vs. Temperature, $V_{dd} = 5.0 \text{ V}$

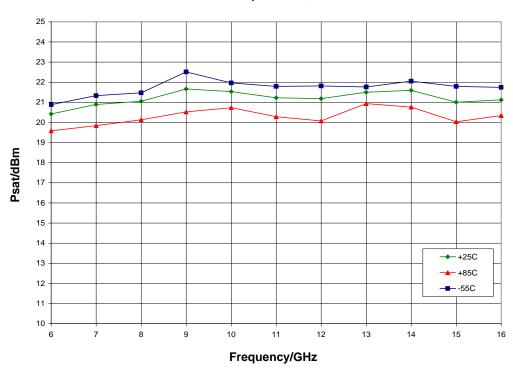


P1dB vs. V_{dd} , $T_A = 25^{\circ}$ C

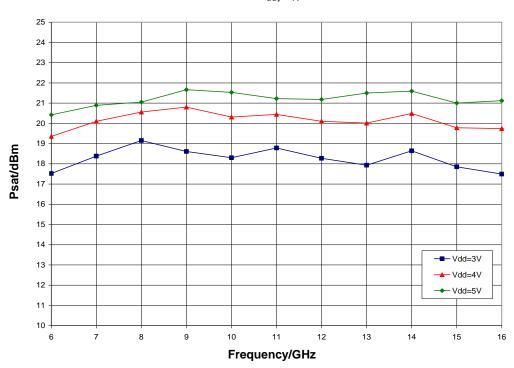




Psat vs. Temperature, $V_{dd} = 5.0 \text{ V}$

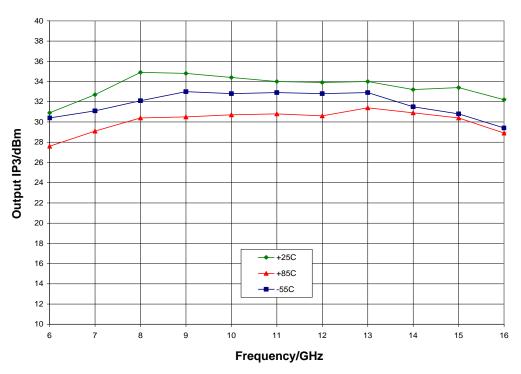


Psat vs. V_{dd} , $T_A = 25^{\circ} C$

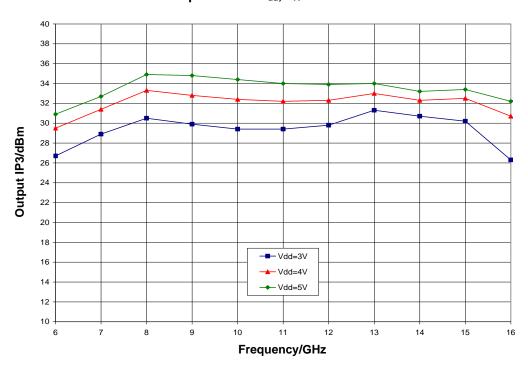




Output IP3 vs. Temperature, $V_{dd} = 5.0 \text{ V}$



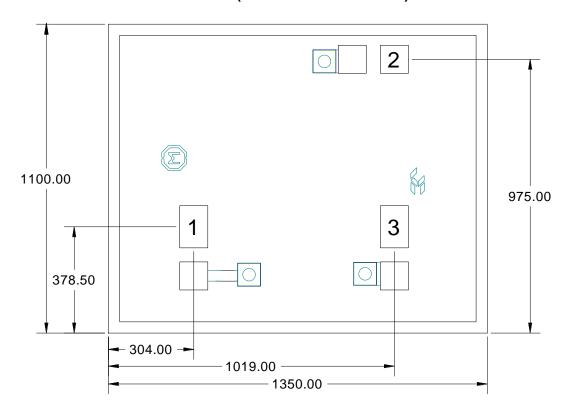
Output IP3 vs. V_{dd} , $T_A = 25^{\circ}$ C





Mechanical Information

Die Outline (all dimensions in microns)



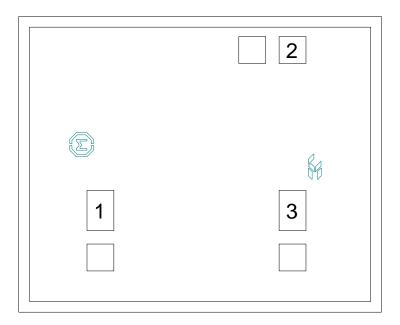
Notes:

- 1. No connection required for unlabeled pads
- 2. Backside is RF and DC ground
- 3. Backside and bond pad metal: Gold
- 4. Die is 100 microns thick
- 5. DC bond pad (2) is 100 x 100 microns
- 6. RF bond pads (1, 3) are 100 x 150 microns



Pad Description

Pad Diagram



Functional Description

Pad	Function	Description	Schematic
1	RF in	DC blocked and 50 ohm matched	RF in O———
2	V _{dd}	Power supply voltage Decoupling and bypass caps required	vdd
3	RF out	DC blocked and 50 ohm matched	
Backside	Ground	Connect to RF / DC ground	GND =



Applications Information

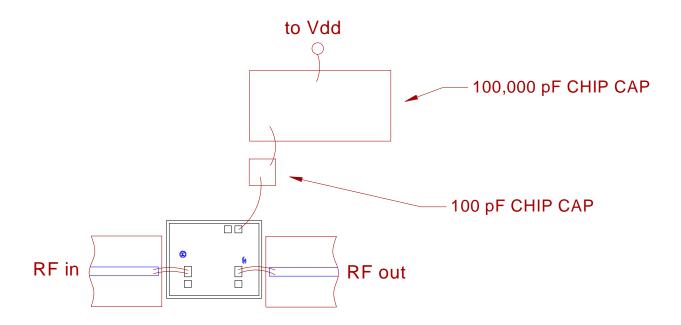
Assembly Guidelines

The backside of the CMD305 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy only. Eutectic attach is not recommended. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines, and the RF decoupling capacitors placed in close proximity to the DC connections on chip.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized. The RF input and output require a double bond wire as shown.

The semiconductor is 100 um thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

Assembly Diagram



GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.



Applications Information

Biasing and Operation

The CMD305 is biased with a positive drain supply. Performance is optimized when the drain voltage is set to +5.0 V, though it may be set to a minimum of +3.0 V.

Turn ON procedure:

1. Apply drain voltage V_{dd} and set to +5 V

Turn OFF procedure:

1. Turn off drain voltage V_{dd}

RF power can be applied at any time.



Handling Precautions

Parameter	Rating	Standard	On Carl
ESD – Human Body Model (HBM)	Class 1A	ESDA / JEDEC JS-001-2012	Caution! ESD-Sensitive Device

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- SVHC Free
- PFOS Free
- Halogen Free



Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: <u>www.qorvo.com</u> Tel: 1-844-890-8163

Email: customer.support@gorvo.com

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